

Freebird “Evolution of Rad Hard GaN Power Technologies” Update 2018

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Freebird Semiconductors 2018 Update to (r)evolutionary GaN power developments demonstrating Radiation Hardness Assured GaN based multi-function/driver modules, discrete GaN HEMT power transistors and RHA validated die elements for the space community. Concentration of Freebird Semiconductors Patented “GaN Driving GaN Technology”.